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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/927,642	08/13/2001	Andrew J. Walker	035905-0103	8019
33971	7590 06/09/2004		EXAMINER	
	SEMICONDUCTOR, I	PERT, EVAN T		
3230 SCOTT BOULEVARD SANTA CLARA, CA 95034			ART UNIT	PAPER NUMBER
5	, on 5000.		2829	
			DATE MAILED: 06/00/2004	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)	
	09/927,642	WALKER ET AL.	N
Office Action Summary	Examiner	Art Unit	
	Evan Pert	2829	
The MAILING DATE of this communication Period for Reply	ation appears on the cover sheet w	vith the correspondence addre	ess
A SHORTENED STATUTORY PERIOD FOR THE MAILING DATE OF THIS COMMUNIC. - Extensions of time may be available under the provisions of after SIX (6) MONTHS from the mailing date of this communication. If the period for reply specified above is less than thirty (30) or If NO period for reply is specified above, the maximum statutes a failure to reply within the set or extended period for reply within the set or extended	ATION. 37 CFR 1.136(a). In no event, however, may a nication. days, a reply within the statutory minimum of thitory period will apply and will expire SIX (6) MO II, by statute, cause the application to become A	reply be timely filed irty (30) days will be considered timely. NTHS from the mailing date of this commuSANDONED (35 U.S.C. § 133).	unication.
Status			
1) Responsive to communication(s) filed	on <u>20 February 2004</u> .		
•	n)⊠ This action is non-final.		
3) Since this application is in condition for closed in accordance with the practice	·	•	erits is
Disposition of Claims			
4) ⊠ Claim(s) <u>1-70</u> is/are pending in the appear 4a) Of the above claim(s) <u>13-18,21-24</u> 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) <u>1-12,19,69 and 70</u> is/are rejected. 7) ☒ Claim(s) <u>20,25 and 26</u> is/are objected. 8) ☐ Claim(s) are subject to restriction.	and 27-68 is/are withdrawn from cted.	consideration .	
Application Papers			
9) The specification is objected to by the 10) The drawing(s) filed on 13 August 200. Applicant may not request that any objection Replacement drawing sheet(s) including the 11) The oath or declaration is objected to be	2 is/are: a)⊠ accepted or b)☐ of to the drawing(s) be held in abeyane correction is required if the drawing	ance. See 37 CFR 1.85(a). g(s) is objected to. See 37 CFR	
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for a) All b) Some * c) None of: 1. Certified copies of the priority do some * Copies of the priority do some * Copies of the priority do some * See the attached detailed Office action	ocuments have been received. ocuments have been received in a the priority documents have been al Bureau (PCT Rule 17.2(a)).	Application No n received in this National Sta	age
Attachment(s)			
 Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO) Information Disclosure Statement(s) (PTO-1449 or PTO) Paper No(s)/Mail Date 	O-948) Paper No	Summary (PTO-413) (s)/Mail Date Informal Patent Application (PTO-15	52)

DETAILED ACTION

Response to Arguments

1. Applicant's arguments, filed February 20, 2004, with respect to the rejection of claims 1-12, 19, 20 and 69 under 35 USC 103(a) have been fully considered and are persuasive (in view of new evidence introduced by applicant after Final Rejection).

Accordingly, the rejection under 35 USC 103(a) has been withdrawn.

However, upon further consideration, a new ground of rejection is made in view of the newly discovered reference to lida et al. (U.S. 5,747,846).

2. In view of the Appeal Brief filed on February 20, 2004, PROSECUTION IS HEREBY REOPENED. A new ground of rejection is set forth below.

To avoid abandonment of the application, appellant must exercise one of the following two options:

- (1) file a reply under 37 CFR 1.111 (since this Office action is non-final); or,
- (2) request reinstatement of the appeal.

If reinstatement of the appeal is requested, such request must be accompanied by a supplemental appeal brief, but no new amendments, affidavits (37 CFR 1.130, 1.131 or 1.132) or other evidence are permitted. See 37 CFR 1.193(b)(2).

Claim Rejections - 35 USC § 102

3. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

⁽b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

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Claims 1, 2, 5, 7, 8, 19, 69 and 70 are rejected under 35 U.S.C. 102(b) as being anticipated by lida et al. (US 5,747,846).

Regarding claim 1, lida et al. discloses a nonvolatile memory array (e.g. col. 9, lines 19-24), comprising: an array of nonvolatile memory devices (e.g. EPROM); at least one driver circuit (e.g. col. 6, lines 11-15); and a substrate (e.g. 1); wherein the at least one driver circuit is not located in a bulk monocrystalline substrate (because it is located in an SOI substrate per col. 6, line 13).

Regarding claim 2, lida et al. point out that "it is preferable to fabricate the [driver] circuit by an SOI process" [col. 6, lines 11-15]. Therefore, the driver circuit is necessarily "in a SOI substrate."

Regarding claim 5, lida et al. disclose wafer bonding as one possible choice [e.g. col. 6, line 63].

Regarding claim 7, the driver is located over monocrystalline substrate 1 (i.e. the substrate which was used to form the SOI substrate having insulator layer 2).

Regarding claim 8, the driver circuit is separated from the substrate 1 by an insulating layer 2.

Regarding claim 19, EEPROM arrays are "one preferred embodiment" (col. 3, lines 59-61).

Regarding claim 69, lida et al. disclose a nonvolatile memory array (e.g. col. 9, lines 19-24), comprising: an array of nonvolatile memory devices (col. 1, lines 17-20); a silicon on insulator substrate (col. 6, lines 51-65); and at least one memory driver circuit located in the silicon on insulator substrate (e.g. col. 6, lines 6-15).

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Regarding claim 70, lida et al. disclose that the nonvolatile memory devices are transistors each comprising a charge storage medium (e.g. "floating gate transistor" per col. 4, lines 46-51 store charge in the floating gate medium).

Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 3-4, 6 and 9-12 rejected under 35 U.S.C. 103(a) as being unpatentable over lida et al. as applied to claim 1 above, and further in view of applicant's admitted prior art of record.

lida et al is silent about "SIMOX," "seeded lateral epitaxy," a polycrystalline silicon on insulator SOI, or that the driver is formed above a "glass," "plastic," or "ceramic" substrate.

However, applicant admits that "SIMOX," "seeded lateral epitaxy," polycrystalline silicon on insulator, and use of plastic, glass and sapphire for SOI substrates were "all known" for making an SOI substrate. Furthermore, applicant does not distinguish anything unexpected among the types of prior art SOI technology contemplated:

Quoting applicant:

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<u>Various</u> techniques are <u>known</u> for forming an <u>SOI substrate</u>. <u>All result in a silicon on an insulator</u>. Depending on the method of formation, the silicon layer can be crystal, polycrystalline, or amorphous. The substrate can be monocrystalline silicon (with an intervening insulator) or some insulating material, such as glass plastic or ceramic. [Brief on Appeal filed February 20, 2004, p. 3, 5th paragraph, emphasis added].

Thus, applicant admits that the limitations of claims 3-4, 6 and 9-12 "all result in a silicon on insulator."

We know that lida et al. specifically disclose the advantage of a driver circuit in a silicon on insulator (SOI) substrate being better "insulating isolation and breakdown voltage" (col. 6, lines 11-15), and also makes the statement that "it is preferable to fabricate the [driver] circuit by an SOI process" [col. 6].

It would have been obvious to one of ordinary skill in the art at the time of the claimed invention to adopt any "known" process for forming an SOI substrate, wherein one would be motivated to reap the benefits of a driver circuit in SOI, being better insulating isolation and breakdown voltage [col. 6, lines 6-15].

Art Recognized Equivalence for the Same Purpose

Applicant's limitations drawn to known methods and materials for "SOI" to not render the claims patentably distinct from lida et al.. Applicant states that "all result in SOI" with respect to claim limitations drawn to material choice and process steps for making a SOI substrate. Since the cited prior art discloses that "SOI is preferable" for a "driver circuit," SOI by any method or material choice can properly be considered an art recognized equivalent, particularly since applicant does not demonstrate anything novel or unexpected by the "known" choices claimed for the "SOI" preferred by lida et al.. Iida directs one of ordinary skill to "SOI" but is silent about all the known equivalents for SOI [See MPEP 2144.06].

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Allowable Subject Matter

5. Claims 25-26 are objected to for depending on a rejected claim, but are otherwise allowable for reasons of record in the last Office Action.

6. Claim 20 is also objected to for depending on a rejected claim, but is now found to be otherwise allowable because claim 20 distinguishes from prior art particularly by the additional limitation that the claimed nonvolatile memory devices (having a driver circuit not located in a bulk monocrystalline substrate) comprise a monolithic three dimensional array of memory devices (wherein lida et al. only disclose written description for a 2-dimensional array of memory devices).

Conclusion

7. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Evan Pert whose telephone number is 703-306-5689. The examiner can normally be reached on M-F (7:30AM-3:30 PM).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Kammie Cuneo can be reached on 703-308-1233. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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ETP May 15, 2004

EVAN PERT
PRIMARY EXAMINER

SUPERVISORY PATENT EXAMINER
TECHNOLOGY CENTER 2800